

Crystal oscillator

### SEIKO EPSON CORPORATION

# CRYSTAL OSCILLATOR (Programmable) OUTPUT: CMOS

- **SG-8200CJ**
- Frequency rangeSupply voltage
- : 1.2 MHz to 170 MHz
- : 1.62 V to 3.63 V
- : Output enable (OE/OE) or Standby (ST/ST)
- Function : Output enable (OE)Frequency tolerance, operating temperature:
  - $\pm 50 \times 10^{-6}$  (-40 °C to +125 °C)
- External dimensions : 2.0 × 1.6 × 0.6 (mm)
- PLL technology to enable setting any output frequency

#### Specifications (characteristics)



Product Number X1G006211xxxx16



Item	Symbol	Specifications			Conditions/Remarks				
Supply voltage	Vcc	1.80 V Typ.	2.50 V Typ.	3.30 V Typ.					
Supply voltage	V CC	1.62 V to 1.98 V	2.25 V to 2.75 V	2.97 V to 3.63 V					
Output frequency range	fo		1.2 MHz to 170 MHz						
Storage temperature	T_stg		-55 °C to +150 °C		Storage as single product	i.			
Operating temperature	T_use		J: -40 °C to +125 °C						
Frequency tolerance <sup>*1</sup>	f_tol		J: ±50 × 10 <sup>-6</sup>		T_use = -40 °C to +125 °	С			
		5.2 mA Typ.	5.4 mA Typ.	5.6 mA Typ.					
		7.0 mA Max.	7.2 mA Max.	7.5 mA Max.	$-1.2 \text{ MHz} \le f_0 \le 25 \text{ MHz}$				
		5.4 mA Typ.	5.7 mA Typ.	6.1 mA Typ.					
		7.3 mA Max.	7.6 mA Max.	8.1 mA Max.	25 MHz < f₀ ≤ 50 MHz				
		5.7 mA Typ.	6.3 mA Typ.	7.0 mA Typ.					
		7.7 mA Max.	8.2 mA Max.	9.1 mA Max.	–50 MHz < f₀ ≤ 75 MHz				
Current consumption	Icc	6.2 mA Typ.	6.9 mA Typ.	7.9 mA Typ.		No load, Ri	se/Fall tim	ie: Default	
		8.2 mA Max.	9.1 mA Max.	10.4 mA Max.	−75 MHz < f <sub>0</sub> ≤ 100 MHz				
	-	6.9 mA Typ.	7.9 mA Typ.	9.1 mA Typ.					
		9.4 mA Max.	10.7 mA Max.	12.4 mA Max.	-100 MHz < f <sub>0</sub> ≤ 125 MHz				
	-	7.8 mA Typ.	9.2 mA Typ.	11.2 mA Typ.					
	-	10.4 mA Max.	12.4 mA Max.	15.0 mA Max.	–125 MHz < f <sub>0</sub> ≤ 170 MHz				
		5.0 mA Typ.	5.0 mA Typ.	5.1 mA Typ.	OE = GND (Active High)				
Output disable current	I_dis	7.2 mA Max.	7.3 mA Max.	7.4 mA Max.	$\overline{OE} = V_{CC}$ (Active Low)				
		0.3 µA Typ.	0.3 µA Typ.	0.5 µA Typ.	ST = GND (Active High)				
Standby current	I_std	15.0 µA Max.	15.0 µA Max.	15.0 µA Max.	$ST = V_{CC}$ (Active Low)				
Symmetry	SYM		45 % to 55 %	ioto premax.		S < 15 nF			
o yninieu y	01W		40 /0 10 00 /0		50 % V <sub>CC</sub> Level, L_CMOS ≤ 15 pF Rise/Fall time				
	Vон		90 % Vcc Min.		Default 'A' Option*2	Other Options	Іон	lol	
Output voltage	VOIT				fo > 125 MHz	B: Faster	-2.0 mA	2.0 mA	
(DC characteristics)					75 MHz < fo ≤ 125 MHz	C: Fast	-1.0 mA	1.0 mA	
	Vol	10 % V <sub>cc</sub> Max.		50 MHz < fo ≤ 75 MHz	D: Slow	-0.5 mA	0.5 mA		
	02				fo ≤ 50 MHz	E: Slower	-0.2 mA	0.2 mA	
Output load condition	L CMOS		15 pF Max.						
•	– V <sub>IH</sub>		70 % V <sub>cc</sub> Min.						
Input voltage	VIL		30 % V <sub>CC</sub> Max.		Pin 1				
			-		Default 'A' Option <sup>*2</sup>	Other Options			
		2.0 ns Max.			fo > 125 MHz	B: Faster			
Rise/Fall time	tr/tf	2.5 ns Max.			75 MHz < fo ≤ 125 MHz	C: Fast	20 % - 80 % V <sub>CC,</sub> L_CMOS = 15 pF		
		4.0 ns Max.			50 MHz < fo ≤ 75 MHz	D: Slow			
		6.0 ns Max.			fo ≤ 50 MHz	E: Slower	1		
Output disable time (OE)	tstp_oe				Measured from the time (		rosses 30	% Vcc	
Output disable time (ST)	tstp_st		1 µs Max.		or measured from the tim	e OE or ST pir	n crosses	70 % Vcc	
Output enable time (OE)	tsta_oe	100	ns + 2 clock cycle	Max.	Measured from the time OE pin crosses 70 % V <sub>CC</sub> or measured from the time OE pin crosses 30 % V <sub>CC</sub>				
Output enable time (ST)	tsta_st		3 ms Max.		Measured from the time ST pin crosses 70 % V <sub>CC</sub> or measured from the time ST pin crosses 30 % V <sub>CC</sub>				
Start-up time	t_str	3 ms Max.		Measured from the time $V_{CC}$ reaches its rated minimum value, 1.62 V					
	tej	1.2 ps Typ.			fo = 25 MHz, Offset frequency: 12 kHz to 5 MHz				
		1.2 ps Typ.			fo = 50 MHz, Offset frequency: 12 kHz to 20 MHz				
		1.2 ps Typ.			fo = 75 MHz, Offset frequency: 12 kHz to 20 MHz				
Phase Jitter		1.2 ps Typ. 1.2 ps Typ.			fo = 100 MHz, Offset frequency: 12 kHz to 20 MHz				
	NF U	1.2 ps Typ. 1.1 ps Typ.			fo = 125 MHz, Offset freq				
		1.1 ps Typ. 1.4 ps Typ.			fo = 150 MHz, Offset freq				
		1.4 pS Typ. 1.5 ps Typ.			fo = 170 MHz, Offset freq	,			
			25 °C, first year						

\*1 Frequency tolerance includes initial frequency tolerance, temperature variation, supply voltage variation, reflow drift, load drift and aging (+25 °C, 1 year). \*2 Default 'A' Rise/Fall time and I<sub>OH</sub>/I<sub>OL</sub> are dependent on programmed frequency.



# Crystal oscillator

#### SEIKO EPSON CORPORATION

Pin description						
Pin	Name	I/O type	Function			
	OE	Input	Output Enable	High <sup>*1</sup> or Open:	Specified frequency output from OUT pin	
		input		Low:	OUT pin is low (pull down with 500 k $\Omega$ ), only output driver is disabled.	
	ŌĒ	Input	Output Enable	Low <sup>*2</sup> or Open:	Specified frequency output from OUT pin	
		Input		High:	OUT pin is low (pull down with 500 k $\Omega$ ), only output driver is disabled.	
1	ST		Standby	High <sup>*1 *3</sup> :	Specified frequency output from OUT pin	
•		Input		Low:	OUT pin is low (pull down with 500 k $\Omega$ ),	
					Device goes to standby mode. Supply current reduces to the least as I_std.	
	ST	Input	Standby	Low <sup>*2 *3</sup> :	Specified frequency output from OUT pin	
				High:	OUT pin is low (pull down with 500 k $\Omega$ ),	
					Device goes to standby mode. Supply current reduces to the least as I_std.	
2	GND	Power	Ground			
3	OUT	Output	Clock output			
4	Vcc	Power	Power supply			
*1 If fixing it at High, please connect to $V_{cc}$ directly.						

\*2 If fixing it at Low, please connect to GND directly. \*3 If necessary to use Open, please select Output Enable function.

Product Name

<u>SG-8200CJ</u> <u>170.00000MHz</u> <u>T</u> J J <u>P</u> <u>A</u> 3 <u>4</u> <u>5</u> <u>6</u> <u>7</u> <u>8</u>

①Model ②Package type (CJ: 2.0 mm × 1.6 mm) ③Frequency ④Supply voltage (T: 1.8 V to 3.3 V Typ.) (5) Frequency tolerance (6) Operating temperature ⑦Function ⑧Rise/Fall time

⑤Fre	equency tolerance / ⑥Operating temperature
JJ	+50 x 10 <sup>-6</sup> / -40 °C to +125 °C

⑦Function					
Ρ	Output Enable (OE)				
Q	Output Enable (OE)				
s	Standby (ST)				
Т	Standby (ST)				

8 Rise/Fall time		
А	Default	
В	Faster	
С	Fast	
D	Slow	
Е	Slower	

External dimensions	(Unit: mm)	Footprint (Recommended)	(Unit: mm)
$2.0\pm0.15$ $4^{4}$ $5^{1}_{0}$ $1^{1}_{0}$			

#### Notes:

In order to achieve optimum jitter performance, the 0.01 µF to 0.1 µF capacitor between V<sub>CC</sub> and GND should be placed. It is also recommended that the capacitors are placed on the device side of the PCB, as close to the device as possible and connected together with short wiring pattern.

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